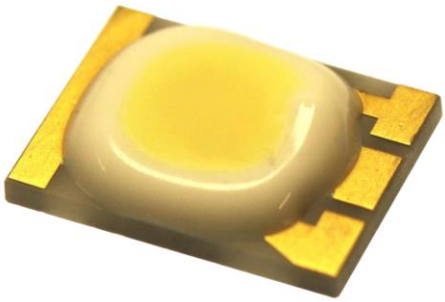
EPIGAP OSA

DATASHEET

OCL-480 GIR-XD



High Power Broadband LED with Glob Top
Visible and Infrared Light Emission

Features:

- Footprint: 6046 (2318)
- Size: 6.0(L) x 4.6(W) x 1.5(H) mm
- Circuit substrate: Ceramics
- ROHS and REACH compliant
- Lead-free solderable
- All devices sorted into intensity classes
- Taped in 16 mm blister tape
- Taping: face-up (T)

Applications:

- Hyperspectral imaging
- Medical tissue analysis
- Halogen Lamp replacement
- Calibration
- Material Analysis
- Sensing

This broadband conversion LED offers a uniquely broad spectrum from 400 nm to 1100 nm. It is designed for hyperspectral imaging, material analysis or halogen lamp replacement. High intensity in the infrared spectral range allows to compensate for sensitivity loss in CMOS sensors.

RoHS COMPLIANT Pb-Free

Typical Electro-Optical Characteristics

Measurement conditions $T_{ambient}$ = 23 °C; t_{test} ≤ 60 ms

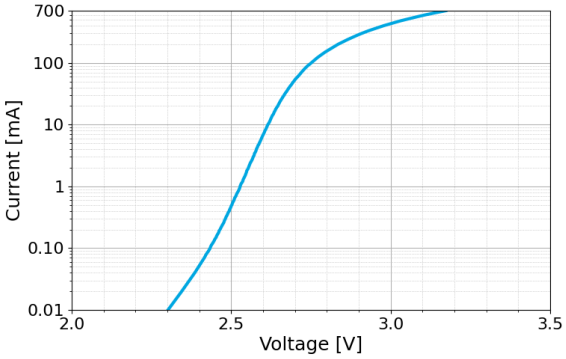
Parameter	Symbol	Condition	Min	Typ	Max	Unit
Emitting Color		Visible and Infrared				
Forward Voltage	V_f	I_f = 350 mA		3.1	3.5	V
		I_f = 700 mA		3.2		
Wavelength Range	λ	I_f = 350 mA	400		1100	nm
Total Radiant Intensity (1)	$I_e = \int_{300}^{1100} I_e(\lambda) d\lambda$	**I_f = 350 mA**		**95**		**mW/sr**
		I_f = 700 mA		**150**		
Radiant Intensity (1, 2) (Conversion)	$I_e = \int_{500}^{1100} I_e(\lambda) d\lambda$	I_f = 350 mA	28	52		mW/sr
		I_f = 700 mA		88		
Total Radiant Power	$I_e = \int_{350}^{1100} I_e(\lambda) d\lambda$	**I_f = 350 mA**		**200**		**mW**
		I_f = 700 mA		**380**		
Radiant Power (Blue Peak)	$I_e = \int_{350}^{490} I_e(\lambda) d\lambda$	I_f = 350 mA		80		mW
		I_f = 700 mA		152		
Radiant Power (Visible w/o Blue Peak)	$I_e = \int_{490}^{700} I_e(\lambda) d\lambda$	I_f = 350 mA		62		mW
		I_f = 700 mA		118		
Radiant Power (Infrared)	$I_e = \int_{700}^{1100} I_e(\lambda) d\lambda$	I_f = 350 mA		58		mW
		I_f = 700 mA		110		
Luminous Intensity	$I_e = \int_{380}^{780} I_e(\lambda) d\lambda$	I_f = 350 mA		12000		mcd
View Angle	θ	I_f = 350 mA		140		deg.
Reverse Current (3)	I_R	V_R = 5 V		--		µA

(1) Measured according to the CIE 127, Condition B
(2) 100% of devices are tested and sorted into intensity groups based on this value
(3) LED should never be operated with reverse bias

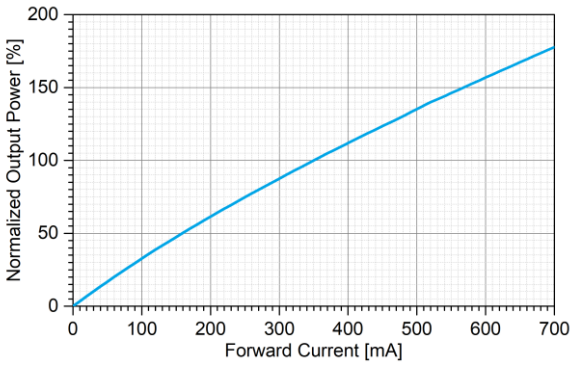
Maximum Ratings

Parameter		Symbol	Min	Max	Unit
Forward Current		$I_{f, max}$		700	mA
Forward Current, pulsed	tp ≤ 100µs, τ=1:10	$I_{f, pulse}$		t.b.d.	mA
Reverse Voltage		V_R		-	V
Thermal Resistance Junction – Solder point		R_{th_JS}		5	K/W
Operating Temperature		T_{op}	-40	+65	°C
Storage Temperature		T_{St}	-40	+85	°C

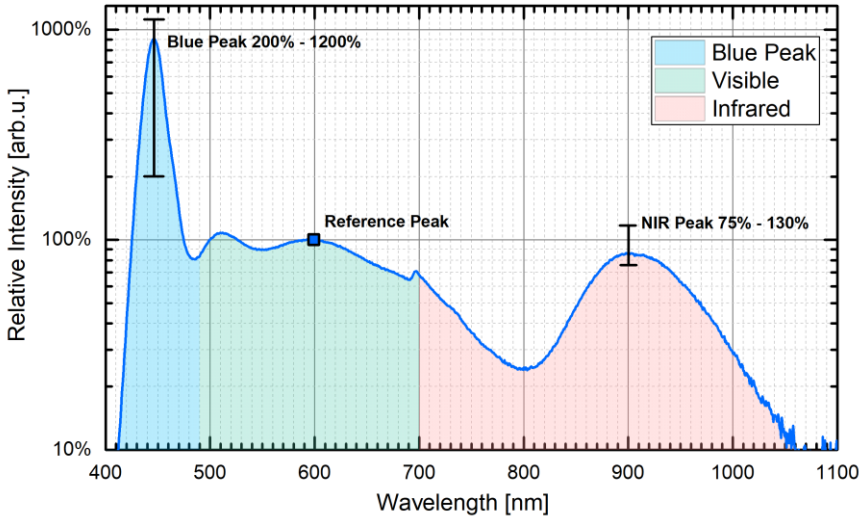
Typical Performance



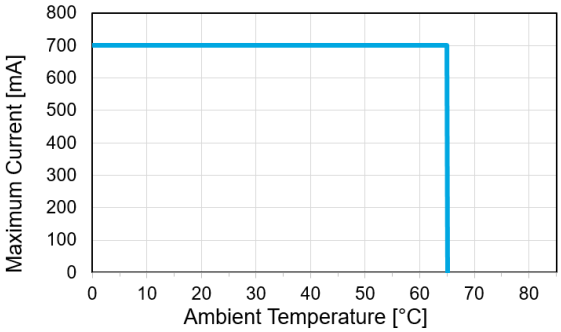
Forward Current vs. Forward Voltage



Relative Intensity vs. Forward Current

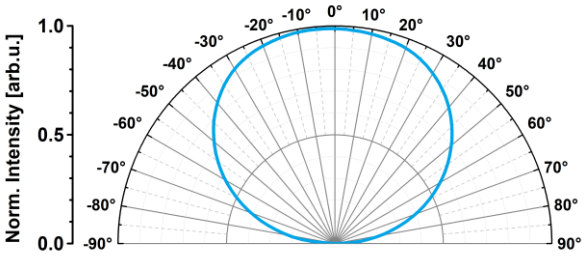


Optical Spectrum



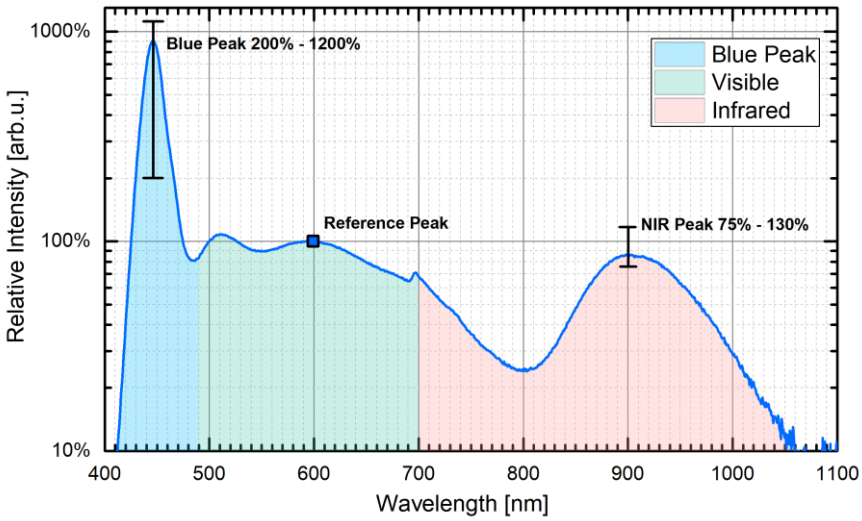
Maximum Ratings (1)

(1) Assuming connection to an infinite heatsink if not stated otherwise



Radiation Pattern

Spectral Characteristics

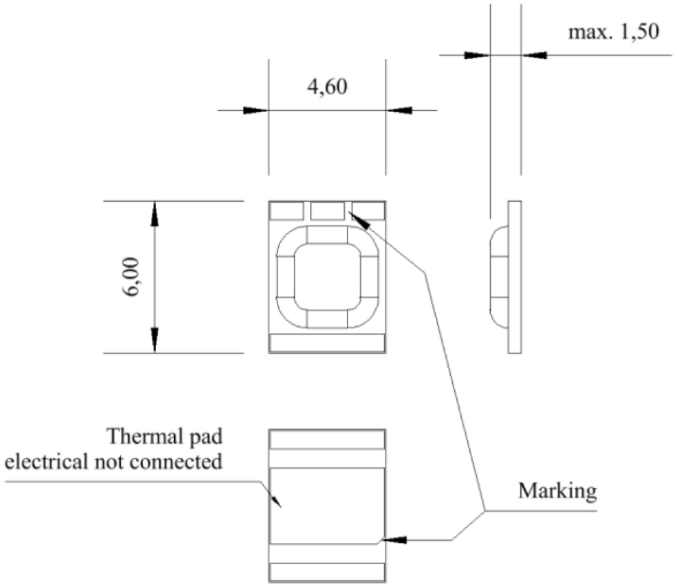


Optical Spectrum

Parameter	Condition	Min	Typ	Max
Blue Peak	$\lambda = 440$ nm	200%		1200%
Visible Light Conversion Peak	$\lambda = 600$ nm		100%	
Infrared Peak	$\lambda = 900$ nm	75%		130%
Blue Peak Integrated Intensity	$I_e = \int_{500}^{1100} I_e(\lambda) d\lambda$		40%	
Visible Integrated Intensity	$I_e = \int_{490}^{700} I_e(\lambda) d\lambda$		31%	
Infrared Integrated Intensity	$I_e = \int_{700}^{1100} I_e(\lambda) d\lambda$		29%	

Outline Drawing

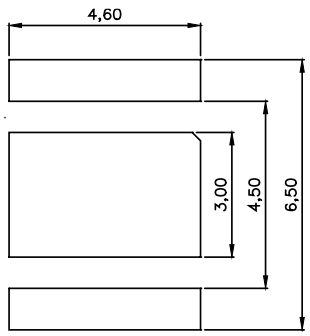
Unless otherwise specified, all drawing units are in mm
Tolerances are: ISO 2768-m



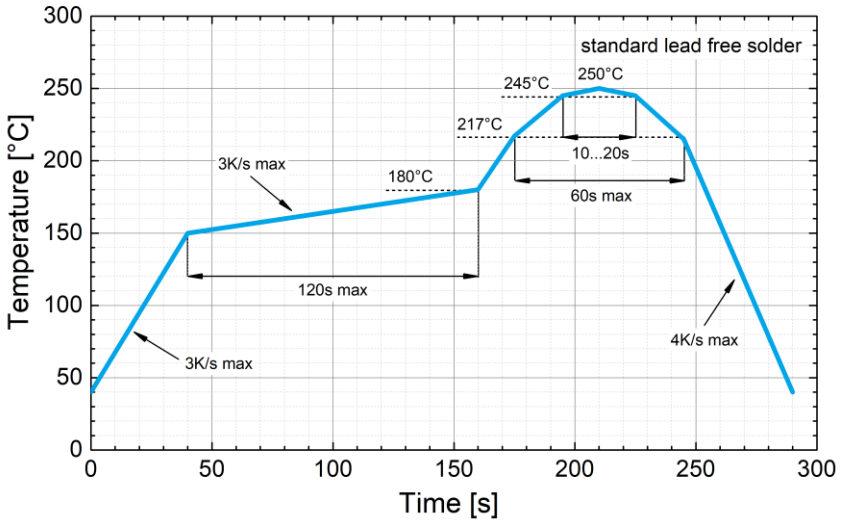
Marking at the Anode side.

Recommended soldering pad

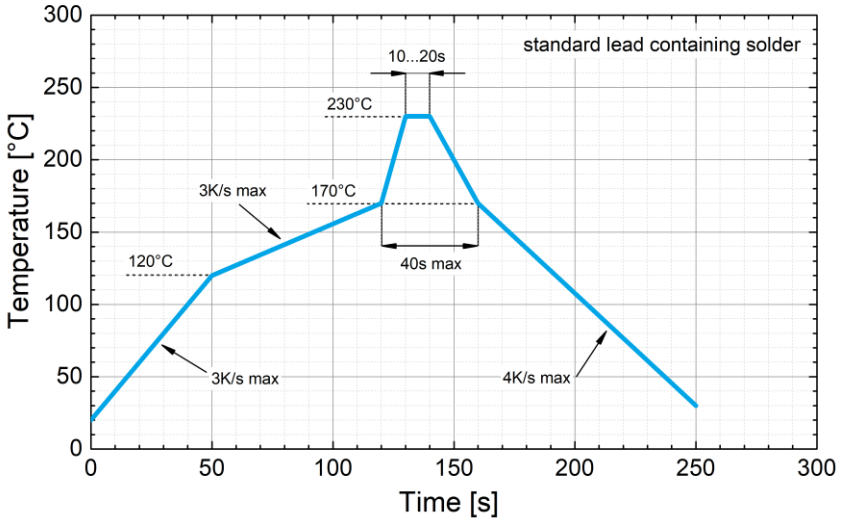
Unless otherwise specified, all drawing units are in mm



Soldering Profile



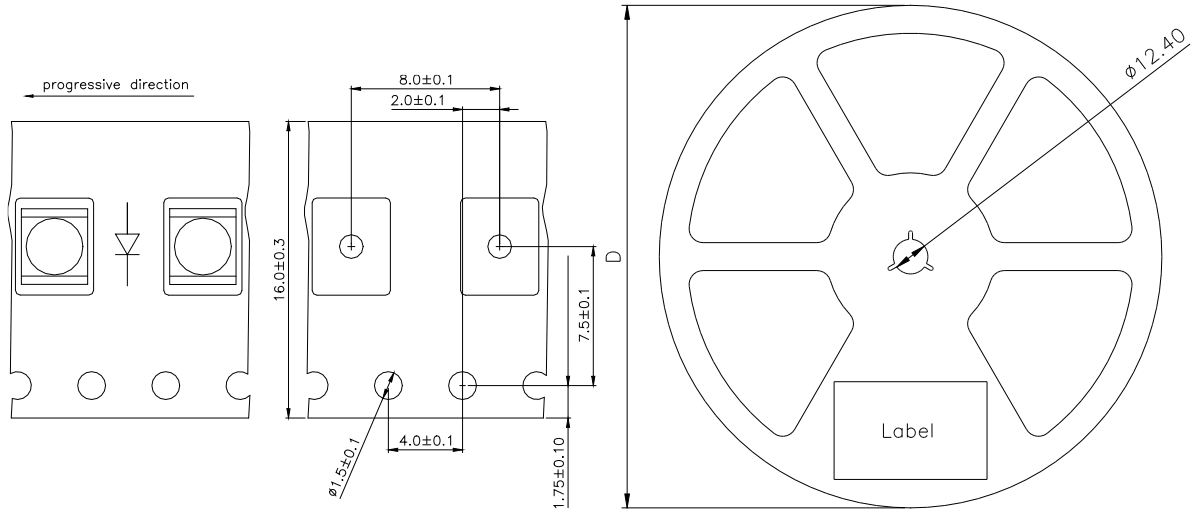
IR reflow soldering profile for lead free soldering



IR reflow soldering profile for solder containing lead

Manual Soldering: Not applicable for manual soldering.

Tape And Reel Packaging



D	Parts/reel
7“	800

Packaging The reel is sealed in a special plastic bag with integrated ESD protection including a silica dry-pack. Shelf life for sealed bag: 12 months on max. 30 °C and 60% Rh. Floor life: 12 months under max. 30 °C and 60% Rh in a dust free environment. Other bags (i.e. MBB, HIC, Vacuum pack, etc.) available on request.

LED Intensity Groups [mW/sr]

All SMD-LED devices are 100% measured and sorted into intensity groups with an accuracy of ± 11 %.
Intensity group is measured according to CIE 127.

General information – not this specific device.

C:	0.28	-	0.45
D:	0.45	-	0.71
E:	0.71	-	1.12
F:	1.12	-	1.80
G:	1.80	-	2.80
H:	2.80	-	4.50
J:	4.50	-	7.10
K:	7.10	-	11.20
L:	11.20	-	18.00
M:	18	-	28
N:	28	-	45
P:	45	-	71
Q:	71	-	112
R:	112	-	180
S:	180	-	280
T:	280	-	450
U:	450	-	710
V:	710	-	1120
AW:	1120	-	1800
BW:	1800	-	2800
CW:	2800	-	4500
DW:	4500	-	7100
EW:	7100	-	11 200
FW:	11 200	-	18 000
GW:	18 000	-	28 000
HW:	28 000	-	45 000
JW:	45 000	-	71 000
KW:	71 000	-	112 000
LW:	112 000	-	180 000
MW:	180 000	-	280 000

Special service: EPIGAP OSA offers Radiant intensity selection (binning) in sub selections.
Color selection in 3 sub-selections possible (each subgroup on a separate reel).
Information on available sub-groups can be accessed through this link:
https://www.epigap-osa.com/datasheet/SMD_LED_Intensity_Groups_And_Subgroups_EPIGAP_OSA.pdf

Notice

The information describes the type of component and shall not consider as assured characteristics. Terms of delivery and rights to change reserved. The data sheet may change without prior notification; the only valid issue and current revision can be on our website. Due to technical requirements, components may contain dangerous substances.
It is the responsibility of the customer to evaluate and ensure that the use of the products in their specific applications complies with relevant safety standards and regulations. Customers must assess the exposure conditions within their systems and ensure that appropriate measures are taken to prevent exceeding the permissible exposure limits outlined in IEC 62471. EPIGAP OSA Photonics GmbH does not assume liability for any non-compliance arising from the integration or usage of LEDs in customer systems.
Parameters can vary in different applications. The customer must validate all operating parameters for each application. EPIGAP OSA Photonics GmbH does not have the responsibility for the reliability and the degradation behavior of products made with EPIGAP OSA Photonics GmbH diodes as they depend not only on the product itself but also on the operation, manufacturing or design of the final products. The customer is responsible for ensuring the long-term stability of the product according to their requirements. If components are used in toys or life support systems, EPIGAP OSA Photonics GmbH must expressly authorize the use of the components prior to incorporating them into the customer's systems!
Packaging: EPIGAP OSA Photonics GmbH uses recyclable packages.

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